



10. The method of claim 9, wherein the Tg of the resinous material is 150° C or higher.
11. The method of claim 9, wherein the resinous material is disposed on a printed wiring board, or an inner layer thereof.
12. The method of claim 7, wherein the etching is performed with a composition comprising permanganate.
13. The method of claim 7, further comprising the step of contacting the porous texture of the resinous material with an activator such that the activator is dispersed within pores and on a surface of the resinous material.
14. The method of claim 13, wherein the activator comprises noble metals of Au, Ag, Pt, Pd, Ir, Rh, Ru, Os or mixtures thereof.
15. A method of treating a resinous material comprising contacting the resinous material with a solvent swell composition comprising a lactone consisting of epsilon-caprolactone and gamma-caprolactone in combination with an amide such that the epsilon-caprolactone or gamma-caprolactone and amide are in sufficient amounts to condition the resinous material for porous texturing with an etchant; and contacting the conditioned resinous material with an etchant.
16. The method of claim 15, further comprising the step of etching the porous textured resinous material with an etching composition comprising permanganate.
17. The method of claim 15, further comprising the step of contacting the porous textured resinous material with an activator such that the activator is dispersed within the pores and on a surface of the resinous material.
18. The method of claim 17, wherein the activator comprises a noble, non-noble metal or mixtures thereof.
19. The method of claim 17, further comprising depositing a metal within pores and on the surface of the resinous material such that a continuous metal layer is bonded to the resinous material.

20. The method of claim 15, wherein the resinous material is disposed on a printed wiring board or inner layers thereof.